NSN 5962-01-312-4304

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View Online at https://aerobasegroup.com/nsn/5962-01-312-4304

Overall Length:

0.960 inches

Overall Height:

0.400 inches

Body Length:

0.960 inches

Body Width:

Between 0.220 inches and 0.310 inches

Body Height:

Between 0.130 inches and 0.185 inches

Maximum Power Dissipation Rating:

794.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

3-state output and monolithic and bipolar and schottky and programmed and high impedance and w/enable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

12 input

Case Outline Source And Designator:

D-6 mil-m-38510

Current Rating Per Characteristic:

140.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

85.00 nanoseconds af output megawatts

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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